

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

<b>Applicant(s):</b>	Jack O. Chu, et al.	<b>Examiner:</b>	Unassigned
<b>Serial No:</b>	To be assigned	<b>Art Unit:</b>	Unassigned
<b>Filed:</b>	Herewith	<b>Docket:</b>	YOR920010308US2 (16315A)
<b>For:</b> EPITAXIAL AND POLYCRYSTALLINE GROWTH OF $\text{Si}_{1-x}\text{yGe}_x\text{Cy}$ AND $\text{Si}_{1-y}\text{Cy}$ ALLOY LAYERS ON Si BY UHV-CVD		<b>Dated:</b> February 10, 2004	

Commissioner for Patents  
United States Patent Office  
Alexandria, VA 23313-1450

**PRELIMINARY AMENDMENT**

Sir:

In connection with filing the above-identified application under 37 C.F.R. §1.53(b), applicants submit the following amendments and remarks for consideration by the Examiner and entry of record in the above-identified patent application.

---

**CERTIFICATE OF MAILING BY "EXPRESS MAIL"**

**Express Mailing Label No.: EV244124450US**

**Date of Deposit: February 10, 2004**

I hereby certify that this correspondence is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 C.F.R. § 1.10 on the date indicated above and is addressed to the Commissioner for Patents and Trademarks, Alexandria, VA 22313-1450 on February 10, 2004.

Dated: February 10, 2004

  
\_\_\_\_\_  
Leslie S. Szivos, Ph.D.